

HD74LVC00

Quad. 2-input NAND Gates

REJ03D0341-0300Z (Previous ADE-205-060B (Z)) Rev.3.00 Jul. 22, 2004

Description

The HD74LVC00 has four 2-input NAND gates in a 14 pin package. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)		
HD74LVC00FPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)		
HD74LVC00TELL	TSSOP-14 pin	TTP-14DV	T	ELL (2,000 pcs/reel)		

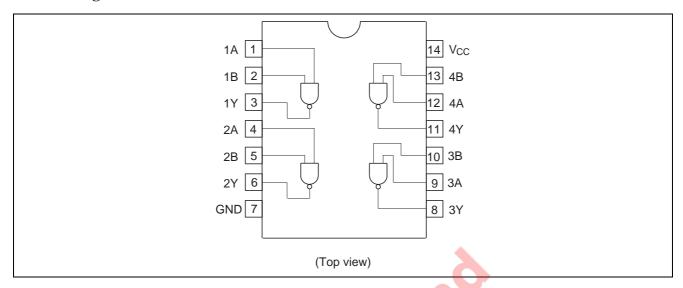
Note: Please consult the sales office for the above package availability.

Function Table

	Inputo		
Α	В	Output Y	
L		Н	
L	Н	Н	
Н	L	Н	
Н	Н	L	

H: High level
L: Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit Conditions
Supply voltage	Vcc	-0.5 to 6.0	V
Input diode current	I _{IK}	-50	$V_1 = -0.5 \text{ V}$
Input voltage	VI	-0.5 to 6.0	V
Output diode current	I _{OK}	-50	mA $V_0 = -0.5 \text{ V}$
		50	mA $V_O = V_{CC} + 0.5 V$
Output voltage	Vo	-0.5 to V _{CC} +0.5	V
Output current	I _o	±50	mA
V _{CC} , GND current / pin	I _{CC} or I _{GND}	100	mA
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	Vcc	1.5 to 5.5	V	Data retention
		2.0 to 5.5		At operation
Input / Output voltage	Vı	0 to 5.5	V	A, B
	Vo	0 to V _{CC}		Y
Operating temperature	Та	-40 to 85	°C	
Output current	lон	-12	mA	$V_{CC} = 2.7 \text{ V}$
		-24* ²		V _{CC} = 3.0 V to 5.5 V
	loL	12		V _{CC} = 2.7 V
		24* ²		V _{CC} = 3.0 V to 5.5 V
Input rise / fall time *1	t _r , t _f	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. Duty cycle \leq 50%.

Electrical Characteristics

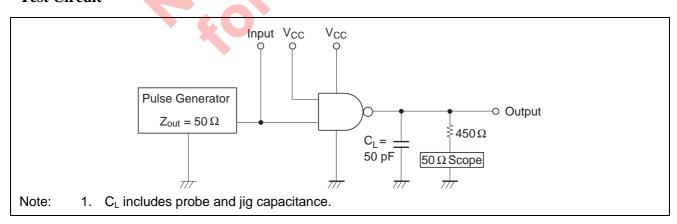
 $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V)	Min	Max	Unit	Test Conditions	
Input voltage	V _{IH}	2.7 to 3.6	2.0	_	V		
		4.5 to 5.5	V _{CC} ×0.7	_	_		
	V_{IL}	2.7 to 3.6	_	0.8			
		4.5 to 5.5	_	V _{CC} ×0.3			
Output voltage	V_{OH}	2.7 to 5.5	V _{CC} -0.2	_	V	$I_{OH} = -100 \mu A$	
		2.7	2.2	_		$I_{OH} = -12 \text{ mA}$	
		3.0	2.4	_			
		3.0	2.0	_		$I_{OH} = -24 \text{ mA}$	
		4.5	3.8	_	_		
	V _{OL}	2.7 to 5.5	_	0.2	V	I _{OL} = 100 μA	
		2.7	_	0.4	_	I _{OL} = 12 mA	
		3.0	_	0.55	_	I _{OL} = 24 mA	
		4.5	_	0.55	_		
Input current	I _{IN}	0 to 5.5	_	±5.0	μΑ	V _{IN} = 5.5 V or GND	
Quiescent supply current	I _{CC}	5.5	_	20	μA	V _{IN} = V _{CC} or GND	
	ΔI_{CC}	3.0 to 3.6	_	500	μA	V_{IN} = one input at (V_{CC} -0.6)V, other inputs at V_{CC} or GND	

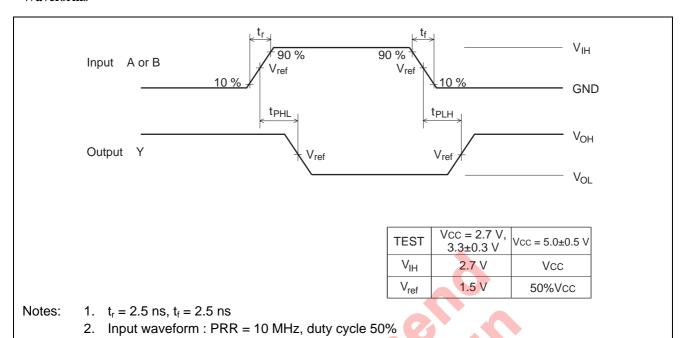
Switching Characteristics

			$Ta = -40 \text{ to } 85^{\circ}C$				From	То
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	2.7	(4)	4.5	7.0	ns	A or B	Υ
	t _{PHL}	3.3±0.3	1.5	3.5	6.0			
		5.0±0.5		3.0	5.5			
Input capacitance	C _{IN}	2.7	-	3.0	_	pF		
Output capacitance	Co	2.7	A	15.0	_	pF		

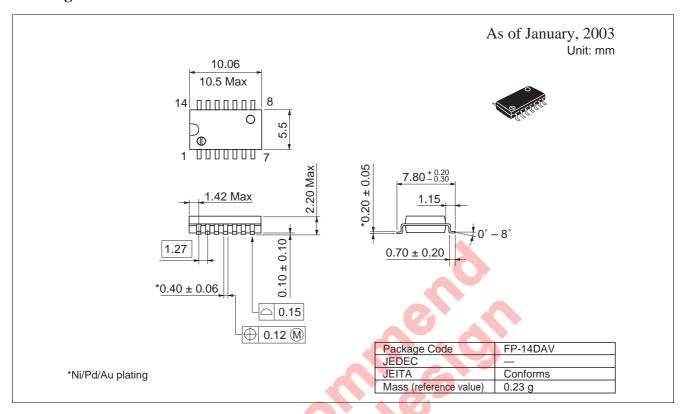
Test Circuit

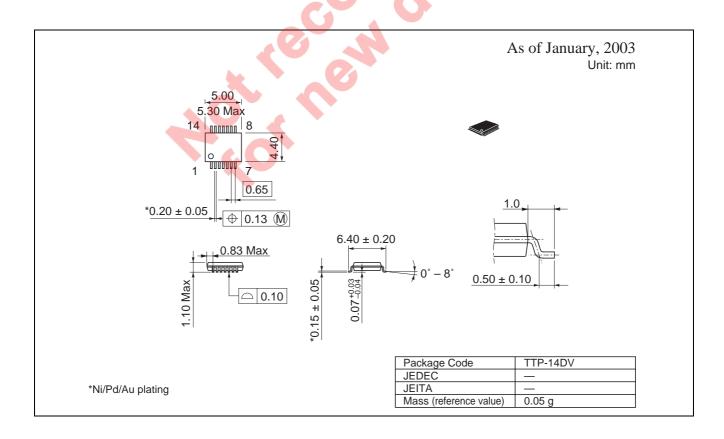


Waveforms



Package Dimensions





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